BAV23 / SE / CC / CA

SURFACE MOUNT SWITCHING DIODES



BAV23



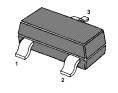
BAV23SE



BAV23CC



BAV23CA



SOT-23 Plastic Package

BAV23SE Marking Code: PY BAV23CC Marking Code: PZ BAV23CA Marking Code: RA

Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Maximum Repetitive Reverse Voltage	V_{RRM}	250	V
Reverse Voltage	V_R	200	V
Forward Current	I _F	400	mA
Repetitive Peak Forward Current	I _{FRM}	625	mA
Non-repetitive Peak Forward Surge Current at t = 1 μs		9	
at t = 100 μs	I _{FSM}	3	Α
at t = 10 ms		1.7	
Power Dissipation	P _D	350	mW
Thermal Resistance Junction to Ambient Air	$R_{ heta JA}$	357	°C/W
Operating Junction and Storage Temperature Range	T _j , T _S	- 65 to + 150	°C

Electrical Characteristics (T_a = 25 °C unless otherwise specified)

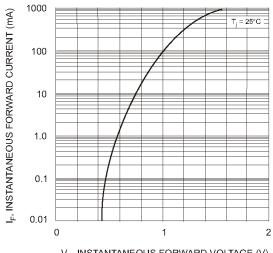
Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at I _R = 100 µA	$V_{(BR)R}$	250	-	V
Forward Voltage at I_F = 100 mA at I_F = 200 mA	V _F	-	1 1.25	V
Reverse Current at V_R = 200 V, T_j = 25 °C at V_R = 200 V, T_j = 150 °C	I _R	-	100 100	nΑ μΑ
Total Capacitance at $V_R = 0 V$, $f = 1 MHz$	C_{T}	-	5	pF
Reverse Recovery Time at $I_F = I_R = 30$ mA, $I_{rr} = 0.1$ X I_R , $R_L = 100$ Ω	t _{rr}	-	50	ns



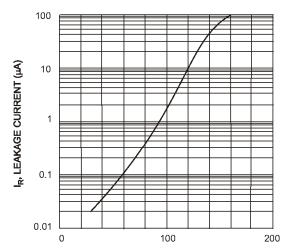




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V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 1 Forward Characteristics



 T_{j} , JUNCTION TEMPERATURE (°C) Fig. 2 Leakage Current vs Junction Temperature











Dated: 04/07/2006